



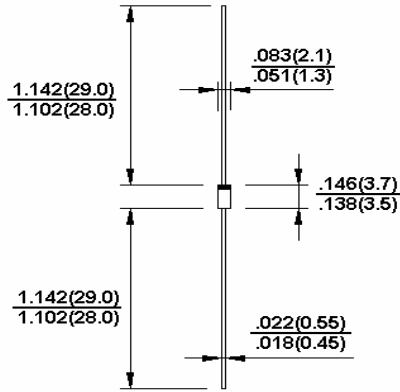
# BAT42 / BAT43

## 200 mW Hermetically Sealed Glass Fast Switching Schottky Barrier Diode

### DO-35

### Features

- ✧ Low forward voltage drop
- ✧ DO-35 package (JEDEC)
- ✧ Through-hole device type mounting
- ✧ Hermetically sealed glass
- ✧ Compression bonded construction
- ✧ All external surface are corrosion resistant and leads are readily solderable
- ✧ RoHS compliant
- ✧ Solder hot dip Tin(Sn) lead finish



Dimensions in inches and (millimeters)

### Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

#### Maximum Ratings

Type Number	Symbol	BAT42/BAT43	Units
Power Dissipation	$P_d$	200	mW
Repetitive Peak Reverse Voltage	$V_{RRM}$	30	V
Maximum DC Blocking Voltage	$V_R$	30	V
Average Forward Rectified Current	$I_{F(AV)}$	200	mA
Peak Forward Surge Current	$I_{FSM}$	4.0	A
Operating and Storage Temperature Range	$T_J, T_{STG}$	-65 to + 125	°C

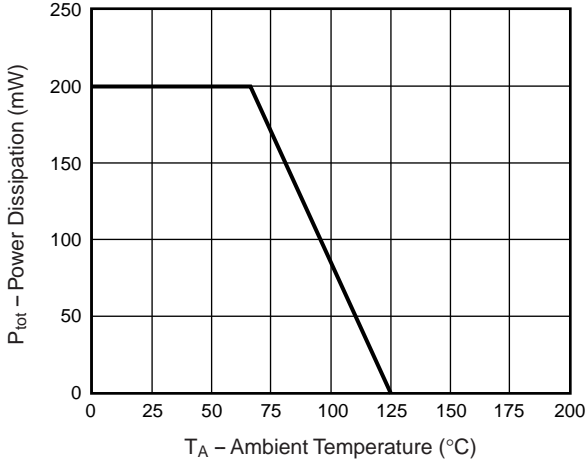
#### Electrical Characteristics

Type Number	Symbol	Min	Max	Units
Breakdown Voltage @ $I_R=100\mu A$	$B_V$	30		V
Forward Voltage Drop All Types	$V_F$			V
BAT42 $I_F=200mA$			1.0	
BAT42 $I_F=10mA$			0.40	
BAT42 $I_F=50mA$			0.65	
BAT43 $I_F=200mA$		0.26	1.0	
BAT43 $I_F=2.0mA$			0.33	
BAT43 $I_F=15mA$		0.45		
Maximum Peak Reverse Current $V_R=25V$	$I_R$		500	nA
Junction Capacitance $V_R=1V, f=1.0MHz$	$C_j$	7(Typ.)		pF
Reverse Recovery Time (Note 1)	$t_{rr}$	5.0 (Typ.)		nS

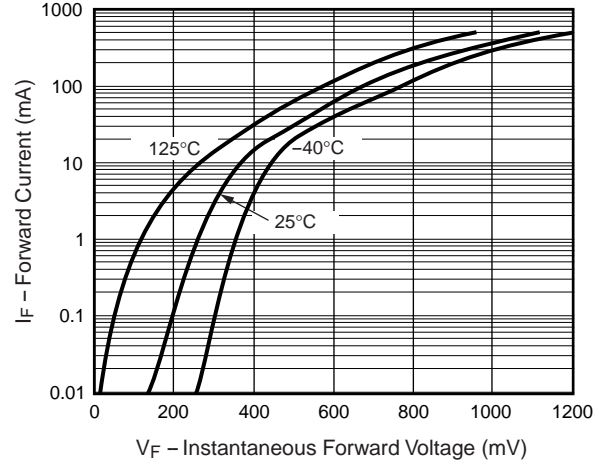
Note: 1. Reverse Recovery Test Conditions:  $I_F=I_R=10mA, I_{RR}=1mA, R_L=100\Omega$ .

RATINGS AND CHARACTERISTIC CURVES (BAT42 /BAT43)

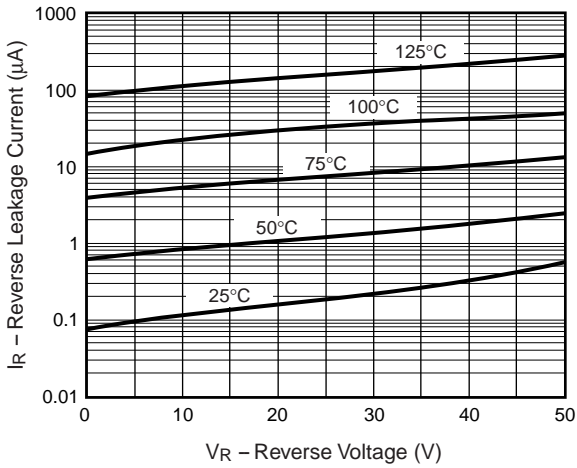
**Fig. 1 – Admissible Power Dissipation vs. Ambient Temperature**



**Fig. 2 – Typical Reverse Characteristics**



**Fig. 3 – Typical Reverse Characteristics**



**Fig. 4 – Typical Capacitance vs. Reverse Applied Voltage**

